

Technical Data Data Sheet N0144, Rev. A

MBR1045S SCHOTTKY RECTIFIER

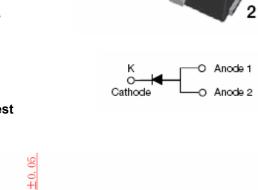
Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

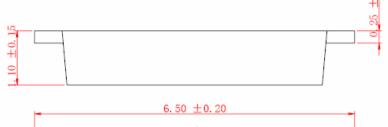
Features:

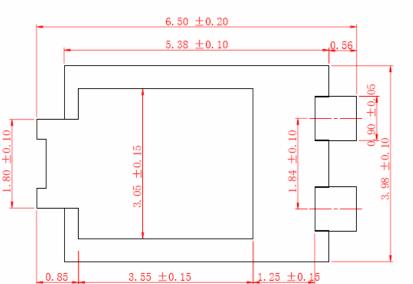
- Designed as Bypass Diodes for Solar Panels
- High Forward Surge Capability
- Ultra Low Forward Voltage Drop
- Excellent High Temperature Stability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In mm



κ







TO-277B

MBR1045S

Green Products

Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 (86) 25-87123907 •
FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •

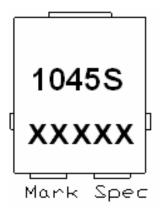


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Marking Diagram:



Where XXXXX is YYWWL

10	= Forward Current (10)
45	= Reverse Voltage (45V)
S	= Device Type
ΥY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
MBR1045S	TO-277B (Pb-Free)	5000pcs/ reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V _{RWM}	-	45	V
Max. Average Forward	I _{F(AV)}	50% duty cycle @T _C =80°C, rectangular wave form	10	A
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	275	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V _{F1}	@ 10A, Pulse, T _J = 25 °C	0.5	V
	V_{F2}	@ 10A, Pulse, T _J = 125 °C	0.45	V
Max. Reverse Current	I _{R1}	$@V_R = rated V_R$	1.0	mA
		T _J = 25 °C		
	I _{R2}	$@V_{R} = rated V_{R}$	15	mA
		$T_J = 100^{\circ}C$		

* Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	TJ	-	-55 to +150	°C
Max. Storage Temperature	T _{stg}	-	-55 to +150	°C
Maximum Thermal	R _{0JC}	DC operation	6.0	°C/W
Resistance Junction to Case				°C/VV
Approximate Weight	wt	-	0.08	g
Case Style		TO-277B		



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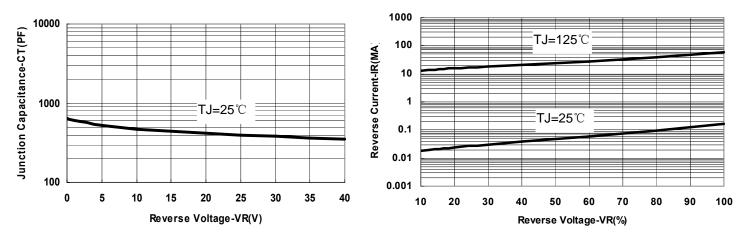




Fig.2-Typical Reverse Characteristics

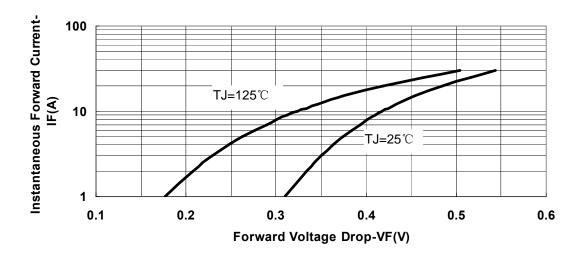


Fig.3-Typical Instantaneous Forward Voltage Characteristics



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